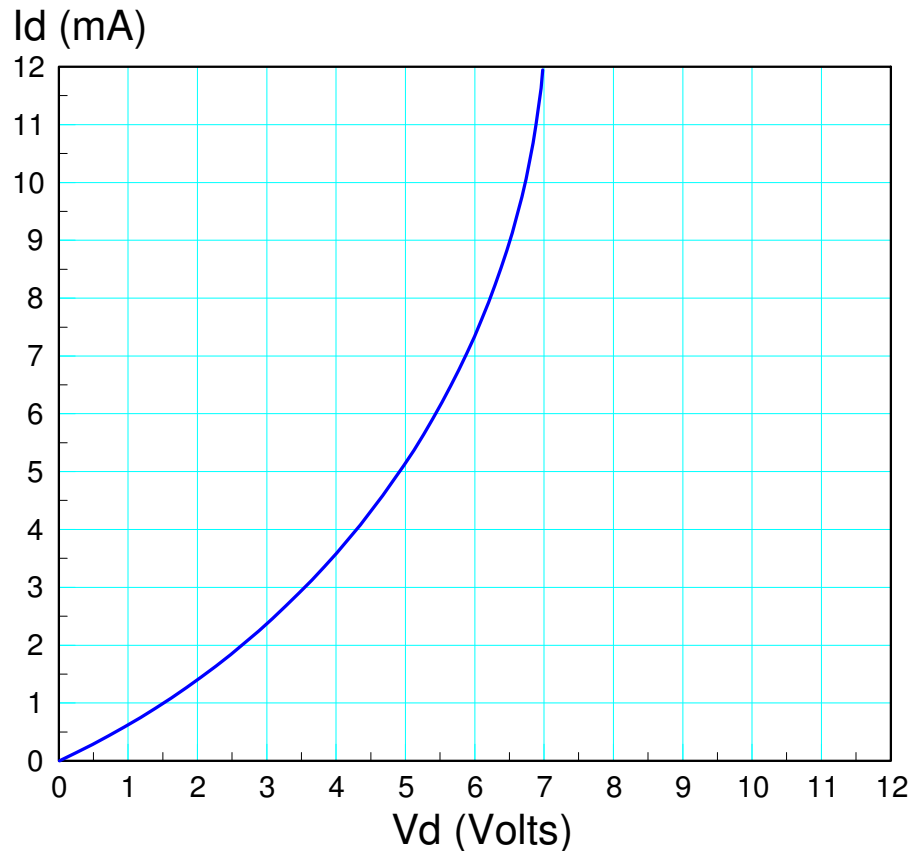
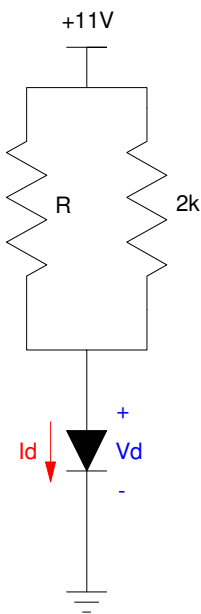


ECE 320 - Final (pt 1) - Name _____

Semiconductors & Diodes

1) Load Lines: Assume the VI characteristics for the diode is as shown in the graph. Draw the load line for the following circuit and determine I_d and V_d . Assume $R = 1000 + 100 * (\text{your birth month}) + (\text{your birth date})$.

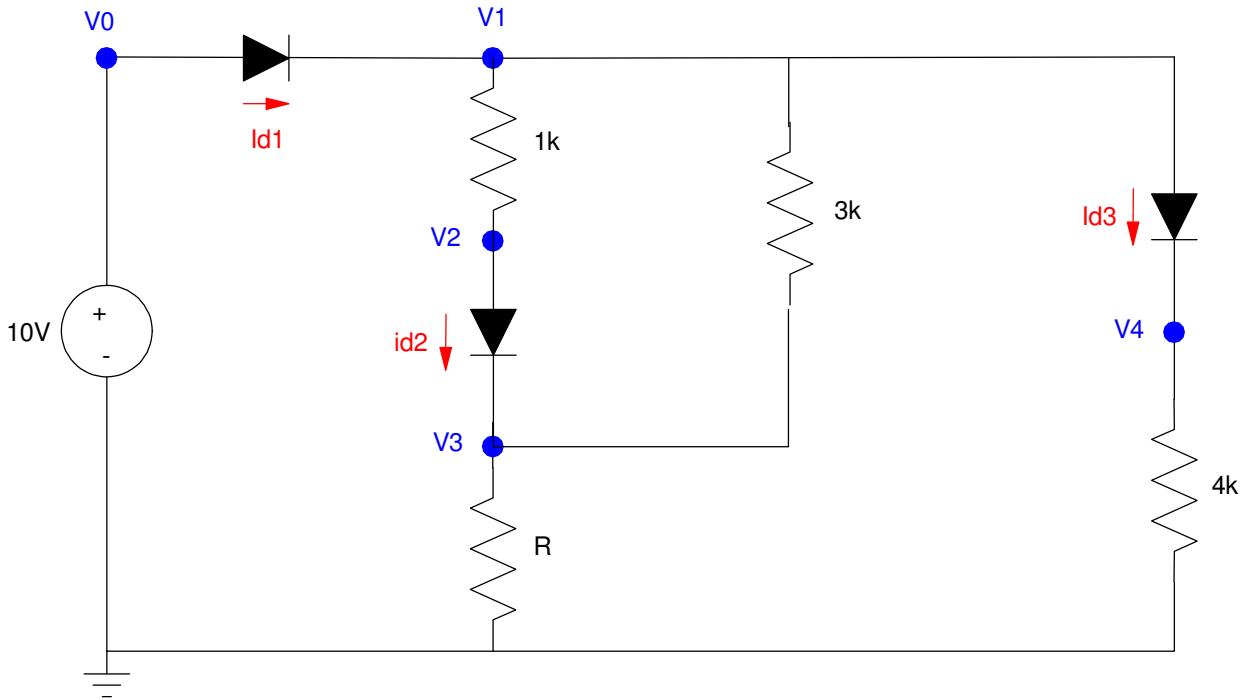
R 1000 + 100*mo + day	Load Line x-intercept (volts)	Load Line y-intercept (mA)	Vd Volts	Id mA



3) Ideal Silicon Diodes. Assume the diodes in this circuit are ideal silicon diodes:

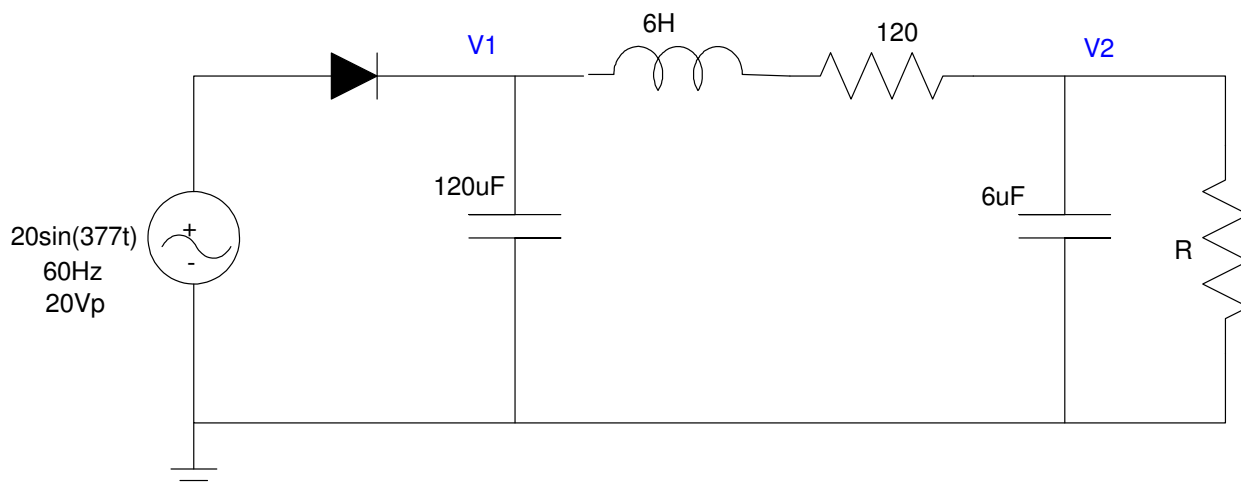
- $V_d = 0.7V$ $I_d > 0$
- $I_d = 0$ $V_d < 0.7V$
- $R = 1000 + 100 * (\text{your birth month}) + (\text{birth date})$. For example, May 14th gives 1514 Ohms.

R	Id1	V1	V2	V3	V4



4) AC to DC: Analysis: Determine V1 and V2 (both DC and AC) for the following AC to DC converter

R	V1		V2	
	DC	AC	DC	AC

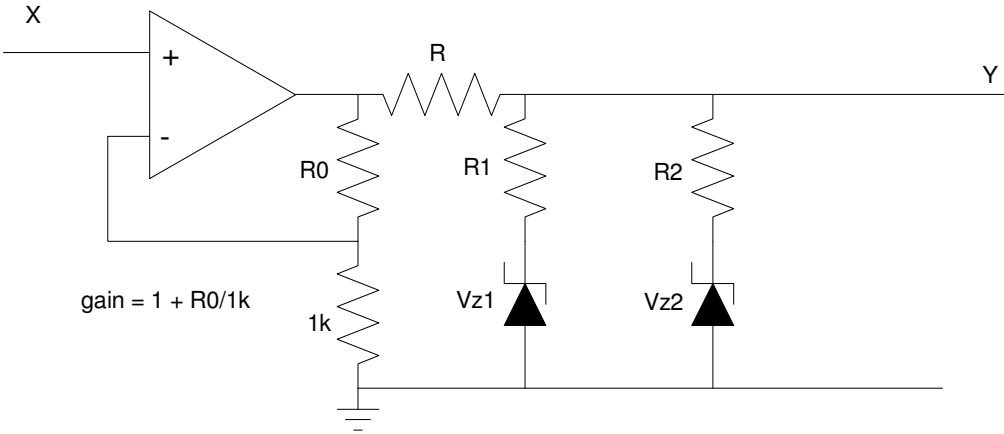
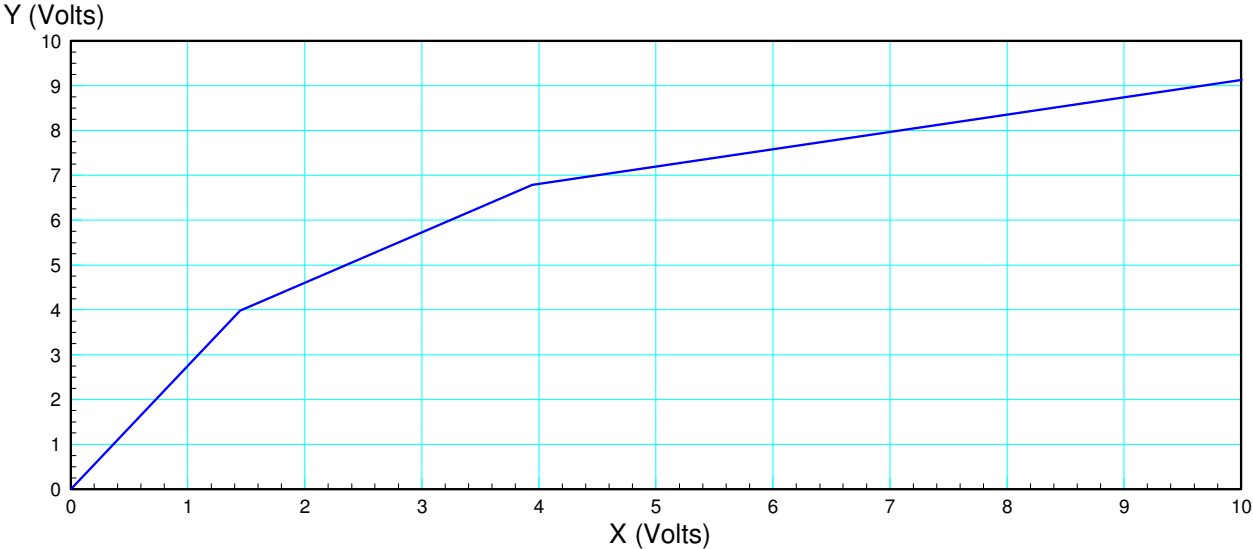


5) Clipper Circuit: Determine the resistors and zener voltages to implement the following function: $Y = f(X)$.

Assume

- Ideal silicon diodes ($V_f = 0.7V$)
- $R = 1000 + 100 * (\text{your birth month}) + (\text{birth date})$

R	R0	R1	Vz1	R2	Vz2
$1000 + 100 * \text{mo day}$					

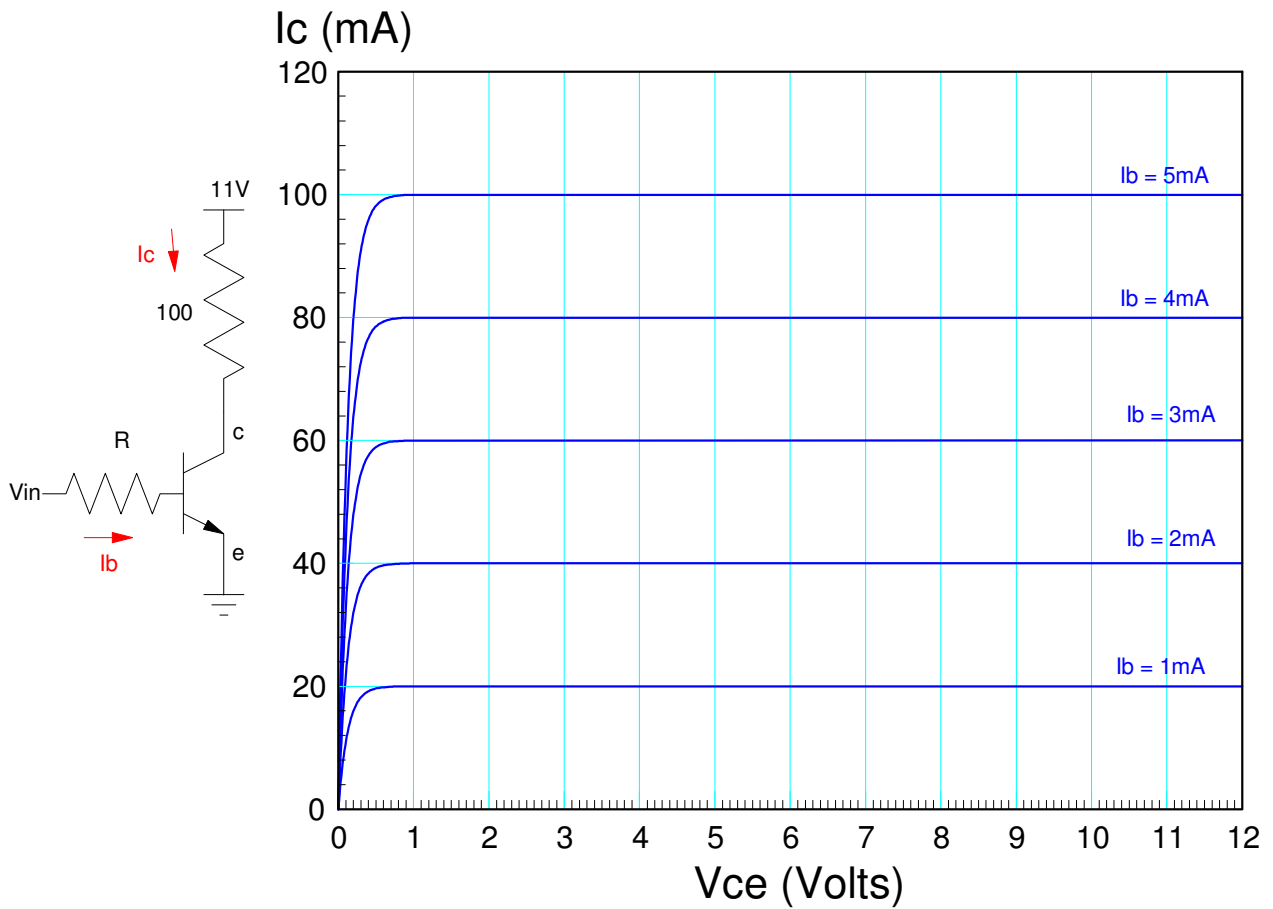


ECE 320 - Final (pt 2) - Name _____

Transistors and Mosfets

6) Determine the current gain, β . Also draw the load line and determine the operating point when $V_{in} = 5V$

R 1000 + 100*Mo + Day	Current Gain hfe = beta	Load Line x-intercept (Volts)	Load Line y-intercept (mA)	Vce Vin = 5V	Ic Vin = 5V

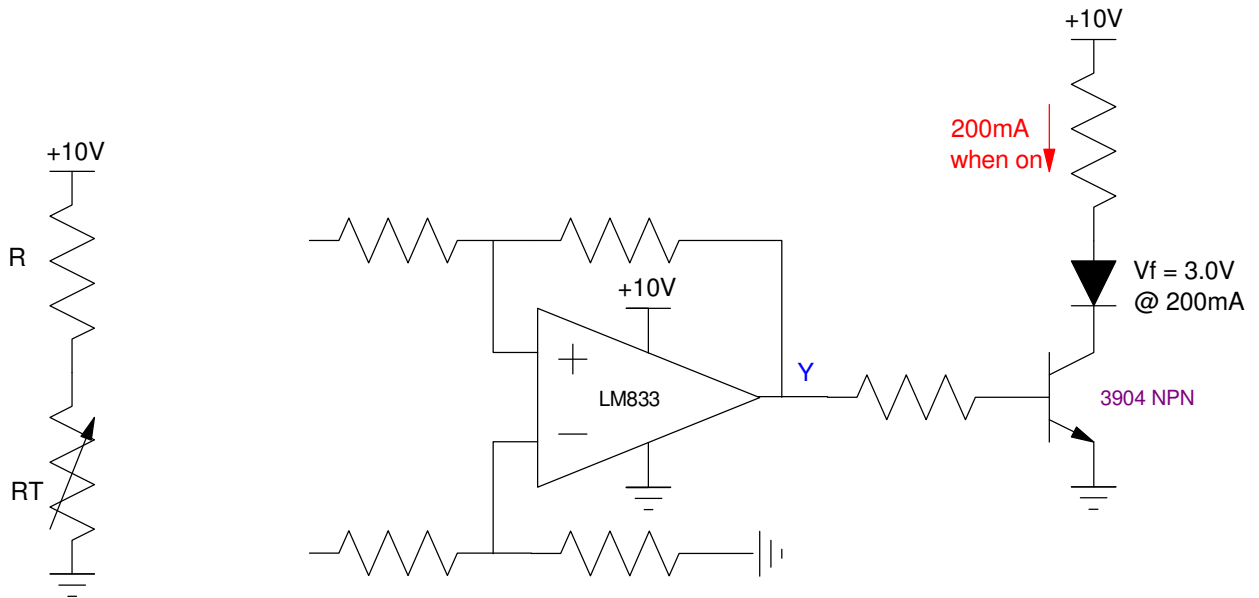


7) Design a Schmitt Trigger & transistor switch so that

- Turns on the LED at 200mA when $R_T > 1500$ Ohms
- Turns off the LED when $R_T < 1200$ Ohms

Assume

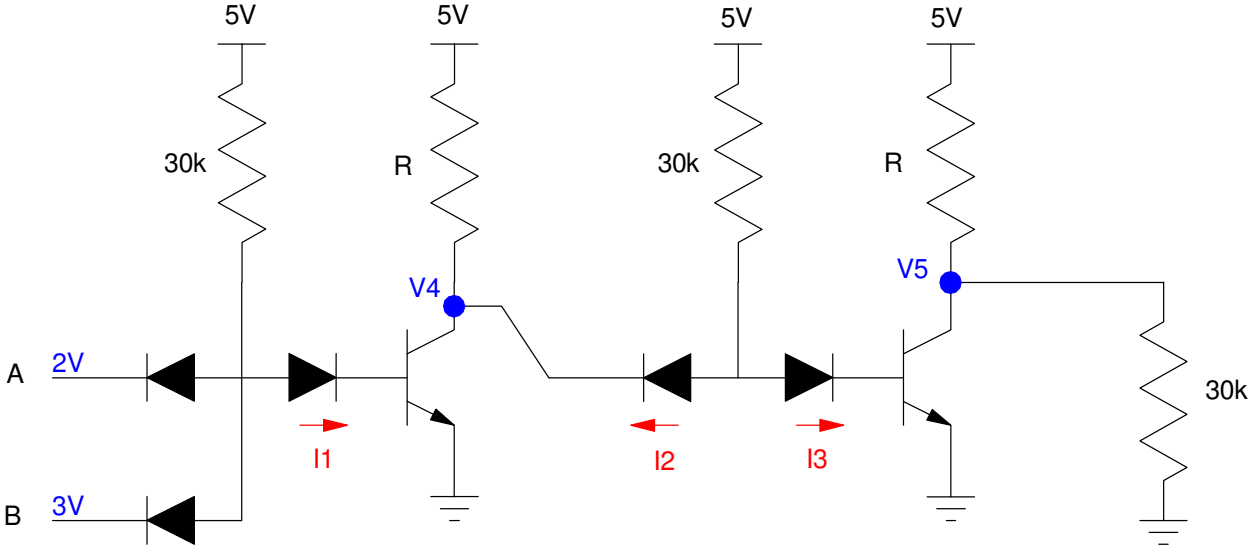
- $R = 1000 + 100 * (\text{your birth month}) + (\text{your birth date})$
- $V_{ce(sat)} = 0.2V$
- Current gain (β) = 100



8) DTL Logic: Determine the voltages and currents for the following DTL logic gage. Assume

- $R = 1000 + 100 * (\text{your birth month}) + (\text{birth day})$
- Ideal silicon diodes ($V_f = 0.7V$), and
- Ideal 3904 transistors ($V_{be} = 0.7V$, $V_{ce(sat)} = 0.2V$, $\beta = 100$)

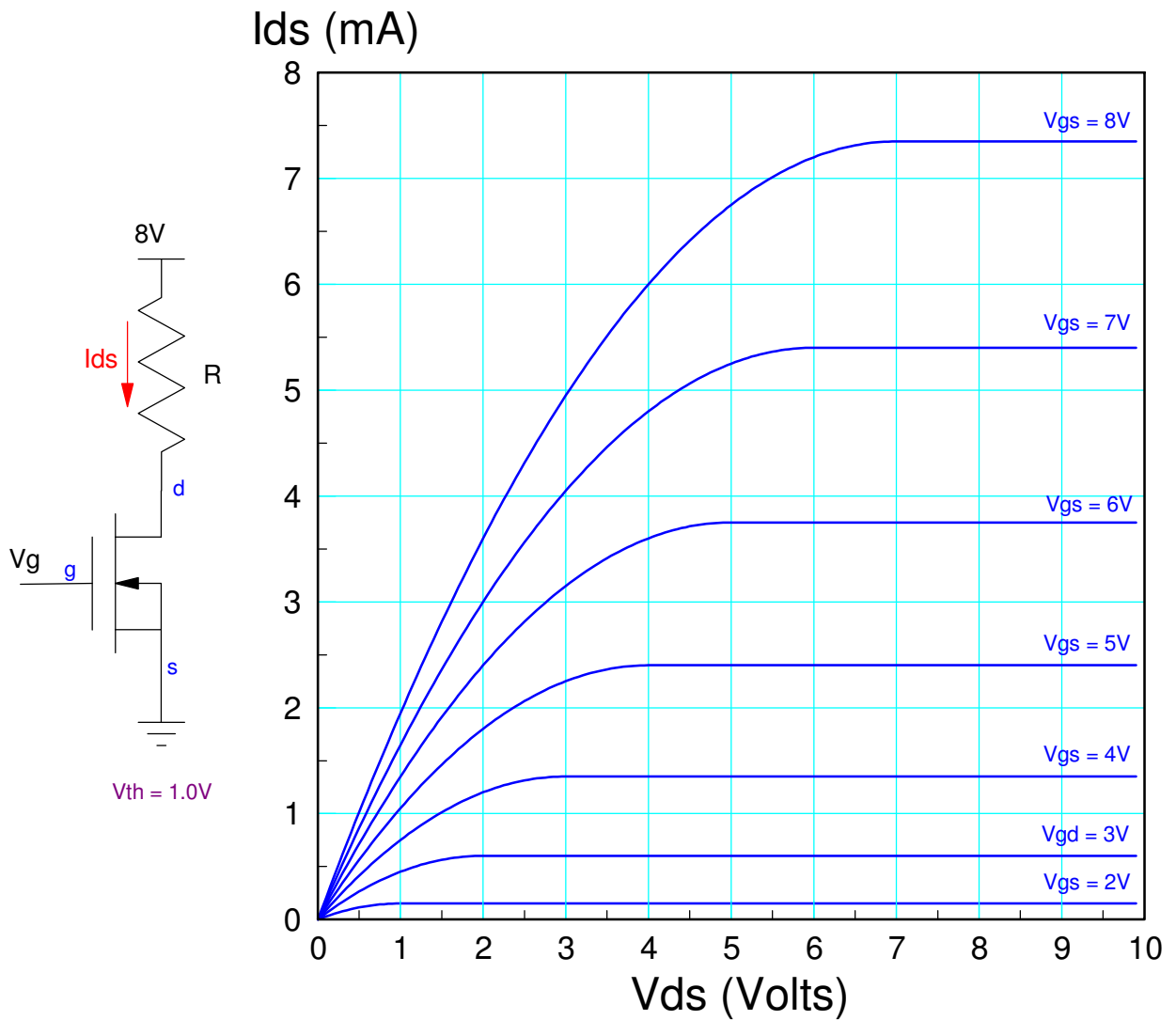
R 1000 + 100*mo + day	I1	I2	I3	V4	V5



9) MOSFET Load Line: For the following MOSFET circuit

- Determine the transconductance gain, k_n ,
- Draw the load line (x and y intercept), and
- Determine $\{V_{ds}, I_{ds}\}$ when $V_g = 7V$

R 1000 + 100*mo + day	k_n transconductance gain	Load Line x=intercept	Load Line y intercept	V_{ds} $V_g = 7V$	I_{ds} $V_g = 7V$	Operating Region off / active / ohmic



10) CMOS Logic

a) Design a CMOS logic gate to implement $Y=f(A,B,C,D)$

		CD			
		00	01	11	10
AB	00	1	1	0	0
	01	1	x	x	0
	11	0	x	x	1
	10	0	0	1	1